

SV15..F

DS4209-4.0 June 2004

Fast Recovery Diode

Replaces January 2000 version, DS4209-3.0

APPLICATIONS

- Induction Heating
- A.C. Motor Drives
- Snubber Diode
- Welding
- High Frequency Rectification
- UPS

FEATURES

- Thermal Fatigue Free Pressure Contact
- High Surge Capability
- Low Recovery Charge

VOLTAGE RATINGS

Type Number	Repetitive Peak Reverse Voltage V _{RRM} V	Conditions
SV15 16F M or K	1600	$V_{RSM} = V_{RRM} + 100V$
SV15 14F M or K	1400	
SV15 12F M or K	1200	
SV15 10F M or K	1000	
SV15 08F M or K	800	
SV15 06F M or K	600	

ORDERING INFORMATION

When ordering, select the required part number shown in the Voltage Ratings selection table, e.g.:

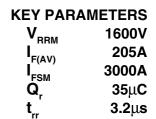
SV15 14FM for an M12 thread

or

SV15 14FK for a 1/2" 20 UNF thread

For stud anode add 'R' to type number, e.g. **SV15 15FMR**. For outline DO8C add suffix 'C' to typ number, e.g. **SV15 15FKC**.

Note: Please use the complete part number when ordering and quote this number in any future correspondance relating to your order.



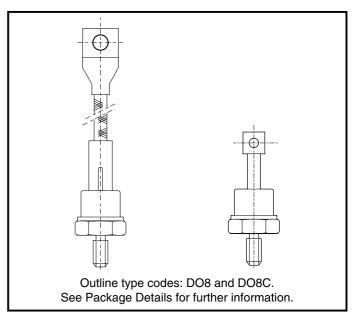


Fig. 1 Package outlines



CURRENT RATINGS

Symbol	Parameter	Conditions	Max.	Units
I _{F(AV)}	Mean forward current	Half wave resistive load, $T_{case} = 65^{\circ}C$	205	А
I _{F(RMS)}	RMS value	$T_{case} = 65^{\circ}C$	236	А

SURGE RATINGS

Symbol	Parameter	Conditions	Max.	Units
I _{FSM}	Surge (non-repetitive) forward current	10 ma half since with $0%/M$ T $150%$	3.0	kA
l ² t	I ² t for fusing	10ms half sine; with 0% $V_{RRM,} T_j = 150^{\circ}C$	45 x 10 ³	A²s

THERMAL AND MECHANICAL DATA

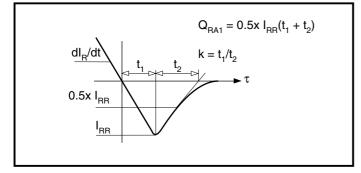
Symbol	Parameter	Conditions	Min.	Max.	Units
R _{th(j-c)}	Thermal resistance - junction to case	dc	-	0.23	°C/W
R _{th(c-h)}	Thermal resistance - case to heatsink	Mounting torque 15Nm with mounting compound	-	0.02	°C/W
T _{vj}	Virtual junction temperature	On-state (conducting)	-	150	°C
T _{stg}	Storage temperature range		-55	200	°C
-	Mounting torque		12.0	15.0	Nm

CHARACTERISTICS

Symbol	Parameter	Conditions	Тур.	Max.	Units
V _{FM}	Forward voltage	At 450A peak, T _{case} = 25°C	-	1.6	v
I _{RRM}	Peak reverse current	At V _{RRM} , T _{case} = 150°C	-	20	mA
t _{rr}	Reverse recovery time	- $I_F = 450A$, $di_{RR}/dt = 10A/\mu s$ - $T_{case} = 125^{\circ}C$, $V_R = 100V$	-	3.2	μs
Q _{RA1}	Recovered charge (50% chord)		-	35	μC
I _{RM}	Reverse recovery current		-	21	А
V _{to}	Threshold voltage	At $T_{vj} = 150^{\circ}C$	-	1.0	V
r _T	Slope resistance	At $T_{vj} = 150^{\circ}C$	-	1.33	mΩ
V _{FRM}	Forward recovery voltage	di/dt = 1000A/µs, T _j = 125°C	-	-	V



DEFINITION OF K FACTOR AND Q_{RA1}



CURVES

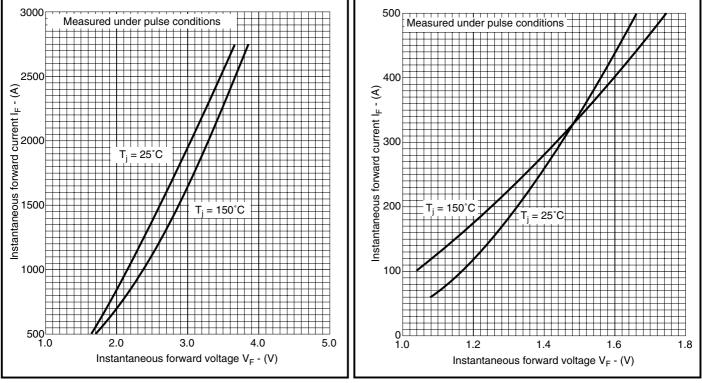
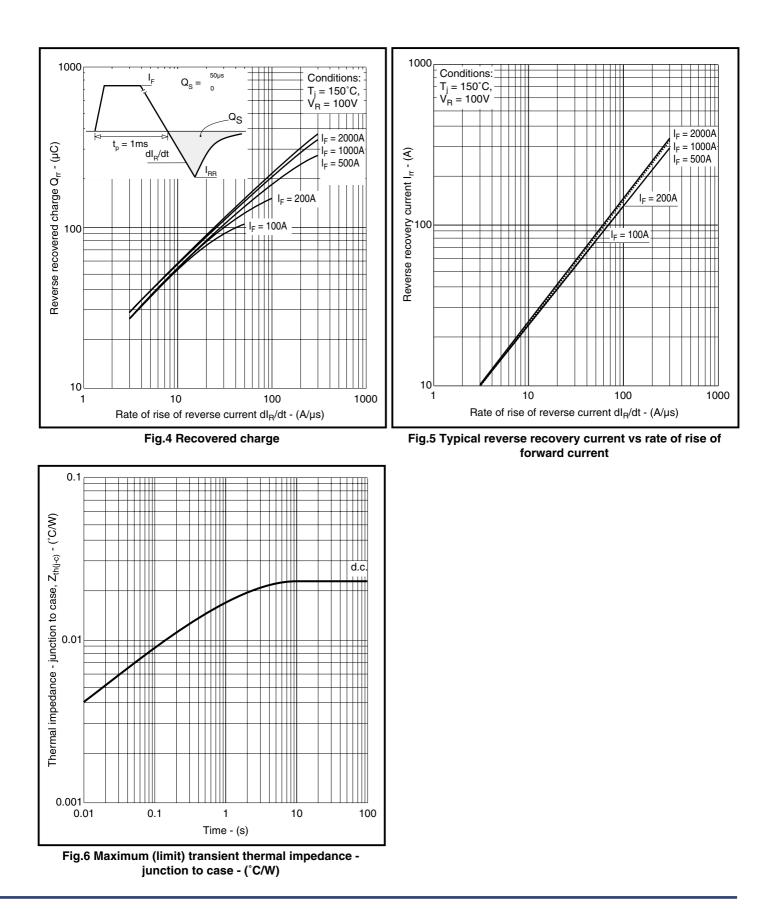




Fig.3 Maximum (limit) forward characteristics

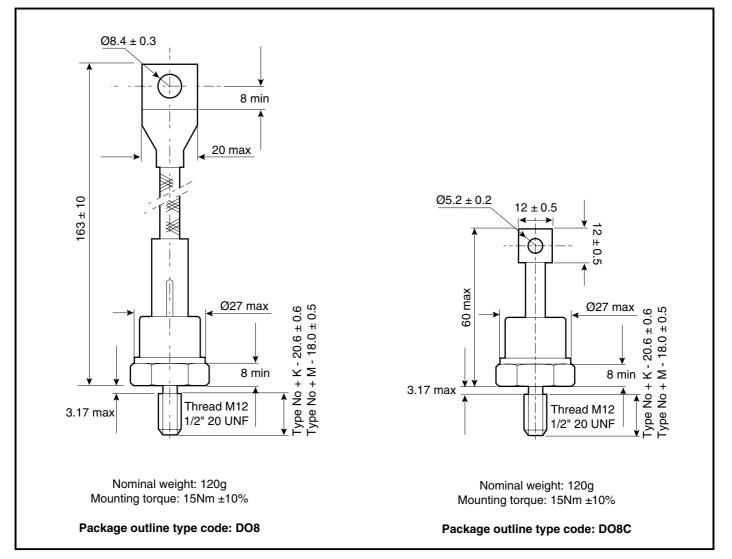






PACKAGE DETAILS - DO8 and DO8C

For further package information, please contact Customer Services. All dimensions in mm, unless stated otherwise. DO NOT SCALE.





POWER ASSEMBLY CAPABILITY

The Power Assembly group was set up to provide a support service for those customers requiring more than the basic semiconductor, and has developed a flexible range of heatsink and clamping systems in line with advances in device voltages and current capability of our semiconductors.

We offer an extensive range of air and liquid cooled assemblies covering the full range of circuit designs in general use today. The Assembly group offers high quality engineering support dedicated to designing new units to satisfy the growing needs of our customers.

Using the latest CAD methods our team of design and applications engineers aim to provide the Power Assembly Complete Solution (PACs).

HEATSINKS

The Power Assembly group has its own proprietary range of extruded aluminium heatsinks which have been designed to optimise the performance of Dynex semiconductors. Data with respect to air natural, forced air and liquid cooling (with flow rates) is available on request.

For further information on device clamps, heatsinks and assemblies, please contact your nearest sales representative or Customer Services.

Stresses above those listed in this data sheet may cause permanent damage to the device. In extreme conditions, as with all semiconductors, this may include potentially hazardous rupture of the package. Appropriate safety precautions should always be followed.



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